

# COMPLEMENTARY SILICON POWER TRANSISTORS

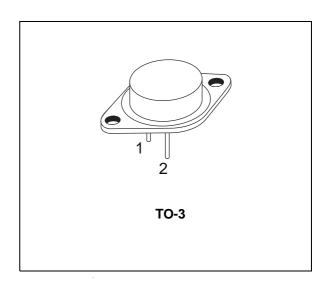
- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY NPN-PNP DEVICES

### **DESCRIPTION**

The 2N3055 is a silicon Epitaxial-Base Planar NPN transistor mounted in Jedec TO-3 metal case

It is intended for power switching circuits, series and shunt regulators, output stages and high fidelity amplifiers.

The complementary PNP type is MJ2955.



# INTERNAL SCHEMATIC DIAGRAM Co (TAB) Bo (1) B (1) Co (TAB) Co (TAB) Co (TAB) Co (TAB) Co (TAB)

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
		NPN	2N3055	
		PNP	MJ2955	
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)		100	V
V <sub>CER</sub>	Collector-Emitter Voltage (R <sub>BE</sub> ≤ 100Ω)		70	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)		60	V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)		7	V
Ic	Collector Current		15	Α
Ι <sub>Β</sub>	Base Current		7	Α
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> ≤ 25 °C		115	W
T <sub>stg</sub>	Storage Temperature		-65 to 200	°C
Tj	Max. Operating Junction Temperature		200	°C

For PNP types voltage and current values are negative.

August 1999 1/4

## THERMAL DATA

R <sub>thj-case</sub> Thermal Resistance Junction-case	Max	1.5	°C/W
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# **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

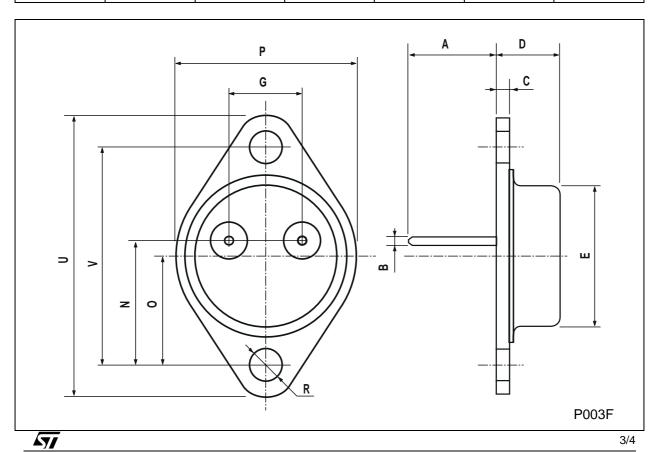
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CEX</sub>	Collector Cut-off Current (V <sub>BE</sub> = -1.5V)	$V_{CE} = 100 \text{ V}$ $V_{CE} = 100 \text{ V}$ $T_j = 150 \text{ °C}$			1 5	mA mA
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	$V_{CE} = 30 \text{ V}$			0.7	mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	$V_{EB} = 7 V$			5	mA
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 200 mA	60			V
VCER(sus)*	Collector-Emitter Sustaining Voltage ( $R_{BE} = 100 \Omega$ )	I <sub>C</sub> = 200 mA	70			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	A		1 3	V
V <sub>BE</sub> *	Base-Emitter Voltage	I <sub>C</sub> = 4 A V <sub>CE</sub> = 4 A			1.8	V
h <sub>FE</sub> *	DC Current Gain	$I_{C} = 4 A$ $V_{CE} = 4 A$ $I_{C} = 10 A$ $V_{CE} = 4 A$	20 5		70	
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 0.5 A V <sub>CE</sub> = 10 V	3			MHz
I <sub>s/b</sub> *	Second Breakdown Collector Current	V <sub>CE</sub> = 40 V	2.87			А

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<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 % For PNP types voltage and current values are negative.

# **TO-3 MECHANICAL DATA**

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	11.00		13.10	0.433		0.516
В	0.97		1.15	0.038		0.045
С	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		0.351
Е	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
N	16.50		17.20	0.649		0.677
Р	25.00		26.00	0.984		1.023
R	4.00		4.09	0.157		0.161
U	38.50		39.30	1.515		1.547
V	30.00		30.30	1.187		1.193



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